

SD101AW - SD101CW

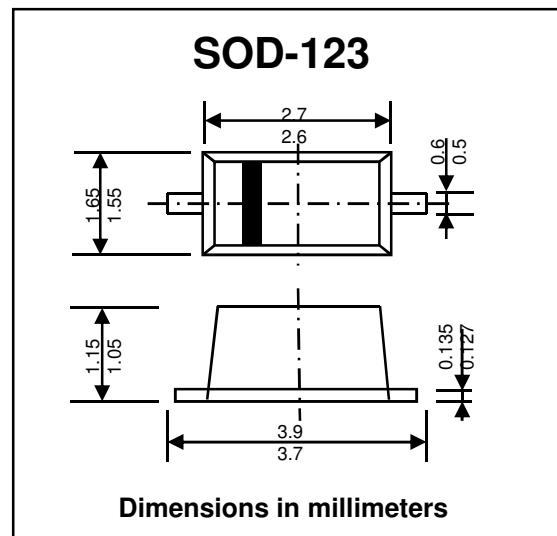
SCHOTTKY BARRIER DIODES

FEATURES :

- * Low Forward Voltage
- * Low Reverse Capacitance
- * Pb / RoHS Free

MECHANICAL DATA :

- * Case : SOD-123 plastic Case
- * Weight : approx. 0.01 g
- * Marking Code : " SM "



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter		Symbol	Value	Unit
Repetitive Peak Reverse Voltage	SD101AW		60	
	SD101BW	V_{RRM}	50	V
	SD101CW		40	
Reverse Voltage	SD101AW		60	
	SD101BW	V_R	50	V
	SD101CW		40	
Forward Continuous Current		I_{FM}	15	mA
Power Dissipation		P_D	400	mW
Maximum Non-Repetitive Peak Forward Surge Current	at $t = 1\text{s}$	I_{FSM}	50	mA
	at $t = 10\text{\mu s}$		2	A
Operating Junction and Storage temperature range		T_J, T_{STG}	-55 to + 150	°C

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Parameter		Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Breakdown Voltage	SD101AW	$V_{(BR)R}$	$I_R = 10\text{\mu A}$	60	-	-	
	SD101BW			50	-	-	V
	SD101CW			40	-	-	
Reverse Current	SD101AW	I_R	$V_R = 50\text{ V}$	-	-	200	
	SD101BW		$V_R = 40\text{ V}$	-	-	200	nA
	SD101CW		$V_R = 30\text{ V}$	-	-	200	
Forward Voltage Drop	SD101AW	V_F	$I_F = 1\text{mA}$	-	-	0.41	
	SD101BW			-	-	0.40	
	SD101CW			-	-	0.39	V
	SD101AW		$I_F = 15\text{mA}$	-	-	1.00	
	SD101BW			-	-	0.95	
	SD101CW			-	-	0.90	
Total Capacitance	SD101AW	C_T	$V_R = 0\text{ V}, f = 1\text{ MHz}$	-	-	2.0	
	SD101BW			-	-	2.1	pF
	SD101CW			-	-	2.2	
Reverse Recovery Time		T_{rr}	$I_F = I_R = 5\text{mA}, I_{rr} = 0.1 \times I_R, R_L = 100\Omega$	-	-	1	ns

RATING AND CHARACTERISTIC CURVES (SD101AW - SD101CW)

Fig.1 - Power Derating Curve

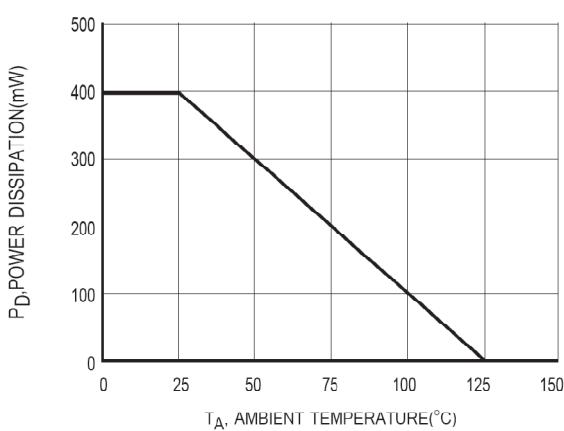


Fig.2 - Typical Total Capacitance
vs Reverse Voltage

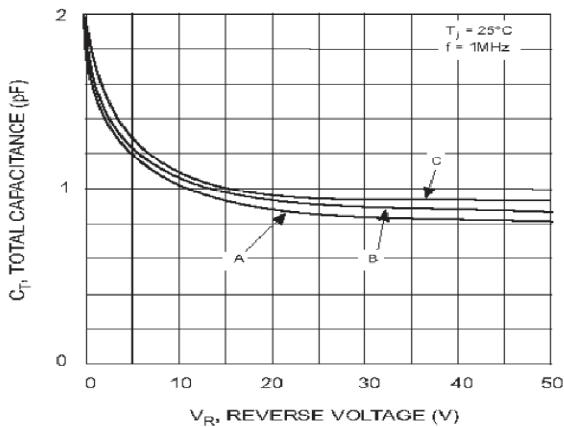


Fig.3 - Typical Forward Characteristics

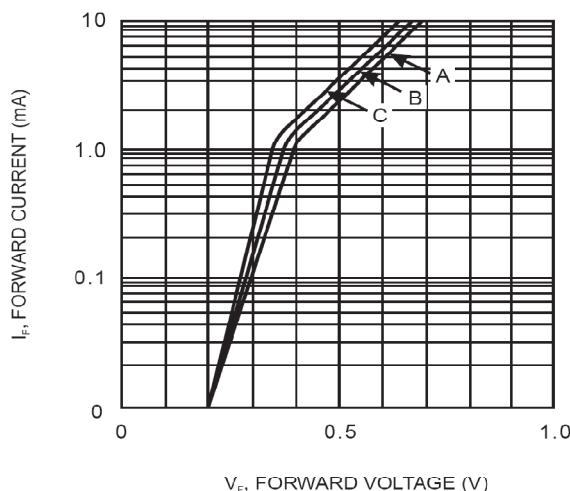


Fig.4 - Typical Reverse characteristics

